MAZMxxxHG Series

Silicon planar type

For surge absorption circuit

■ Features

- Four elements anode-common type
- Power dissipation P_D: 150 mW

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation *	P_{D}	150	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note) *: P_D = 150 mW achieved with a printed circuit board.

■ Package

Code

SSMini5-F3

- Pin Name
 - 1: Cathode 1 4: Cathode 3 2: Anode 1, 2, 3, 4 5: Cathode 4
 - 3: Cathode 2

■ Internal Connection



■ Common Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Symbol		Conditions	N	/lin	Тур	Max	Unit
Zener voltage *	Vz	I_Z	Specified value —					V
Zener rise operating resistance	R _{ZK}	I_Z	Specified value	Refer to the list of the electrical characteristics — within part numbers				Ω
Zener operating resistance	R _Z	I_Z	Specified value				-3	Ω
Reverse current	I_R	V _R	Specified value					μΑ

- Note) 1. Measuring methods are based JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. Electrostatic breakdown voltage is ±10 kV

Test method: IEC1000-4-2 (C = 150 pF, R = 330 Ω , Contact discharge: 10 times)

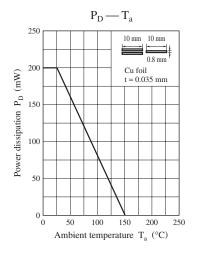
3. *: The temperature must be controlled 25°C for V_Z mesurement.

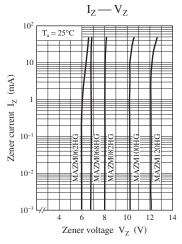
 V_Z value measured at other temperature must be adjusted to $V_Z\,(25^{\circ}\text{C})$

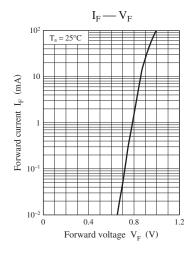
 $\ensuremath{V_{Z}}$ guaranted 20 ms after current flow.

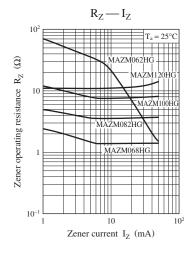
■ Electrical characteristics within part numbers $T_a = 25$ °C ± 3 °C

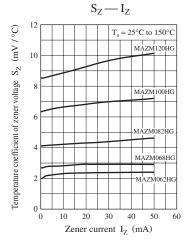
			Reverse current (DC) I _R (μA)		$ \begin{array}{c c} \text{Zener} & \text{Zener rise} \\ \text{operating} & \text{operating} \\ \text{resistance} & \text{resistance} \\ \text{R}_{Z}\left(\Omega\right) & \text{R}_{ZK}\left(\Omega\right) \end{array} $		Marking symbol		
		l		IZ	l	V _R	-	$I_Z = 0.5 \text{ mA}$	
	Min	Nom	Max	(mA)	Max	(V)	Max	Max	
MAZM062HG	5.8	6.2	6.6	5	0.2	4	50	100	6.2Z
MAZM068HG	6.4	6.8	7.2	5	0.1	4	30	60	6.8Z
MAZM082HG	7.7	8.2	8.7	5	0.1	5	30	60	8.2Z
MAZM100HG	9.4	10.0	10.6	5	0.05	7	30	60	10Z
MAZM120HG	11.4	12.0	12.7	5	0.05	9	30	80	12Z

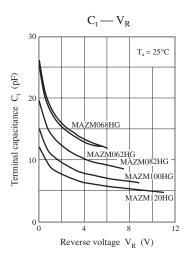






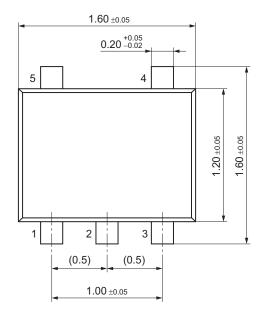


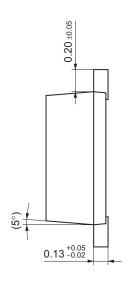


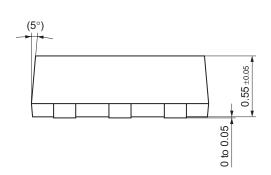


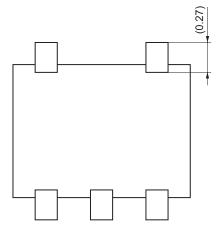
2 SKE00033AED

SSMini5-F3 Unit: mm









SKE00033AED 3

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